

Impact of Impedance effects on beam chamber specifications

LHC 27 km

CERN Préves

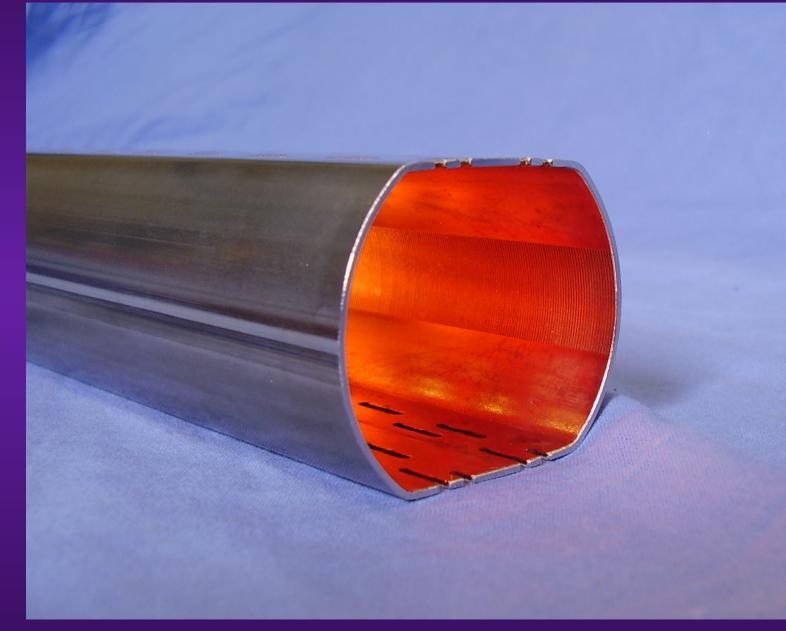
Elias Métral

BE/ABP-HSC (Collective/Coherent Effects)

Elias.Metral@cern.ch Tel.: 00 41 75 411 4809 http://emetral.web.cern.ch/emetral/

CERN Mewrin

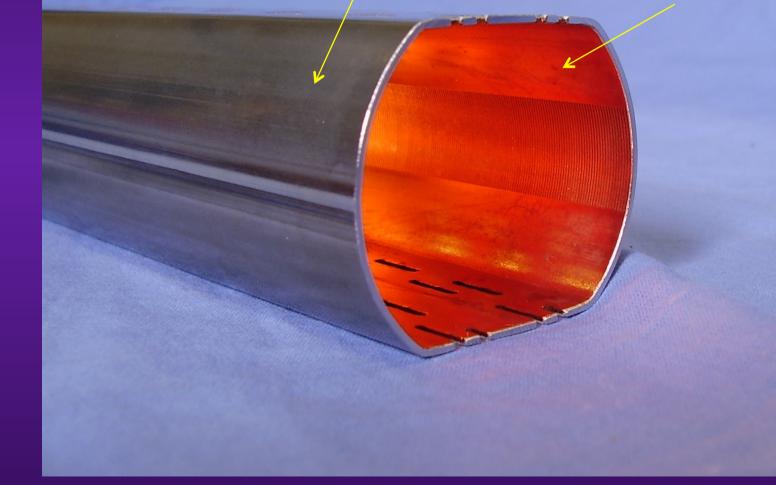
ATLA





Beam screen tube (Stainless-Steel: SS)

Copper coating



Beam screen tube (Stainless-Steel: SS)

Copper coating

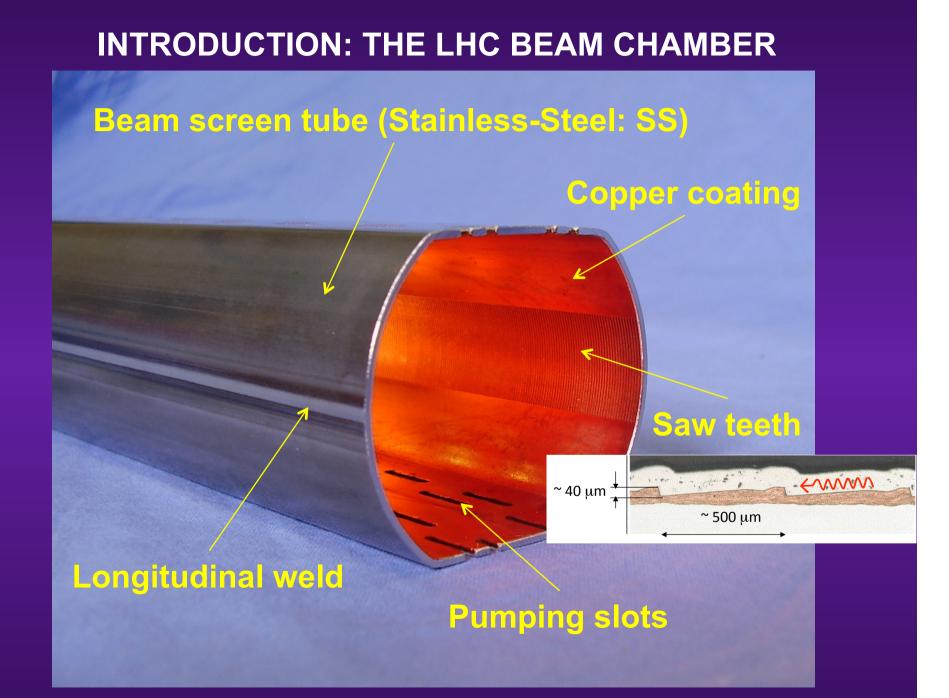
Longitudinal weld

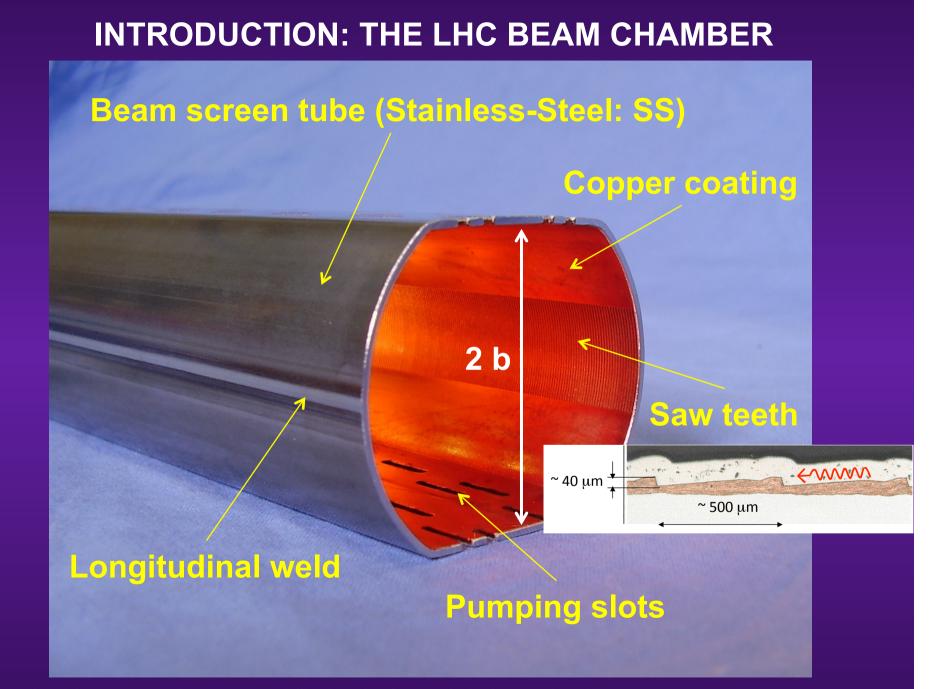
Beam screen tube (Stainless-Steel: SS)

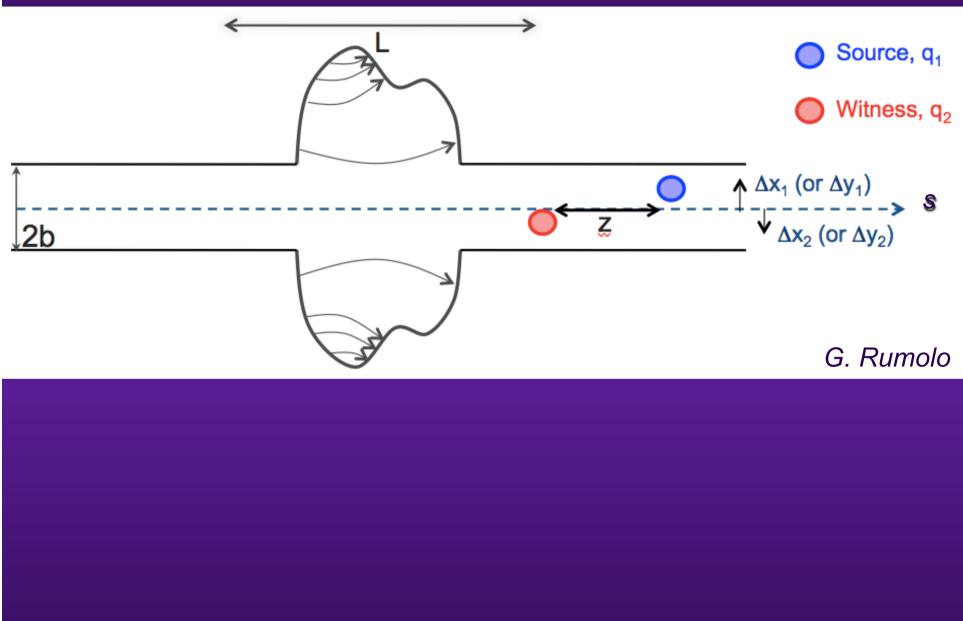
Copper coating

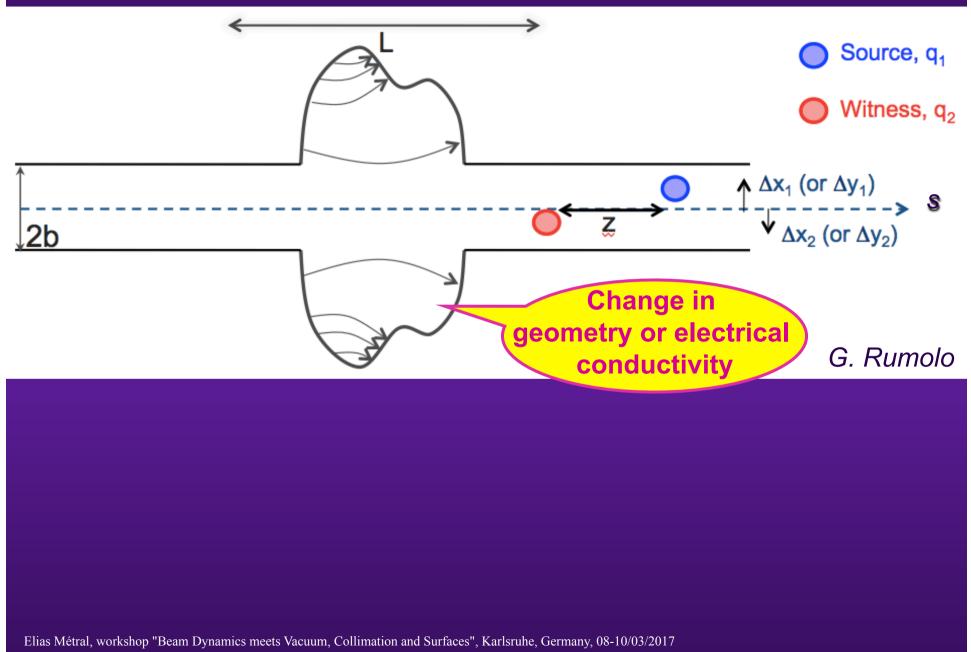
Longitudinal weld

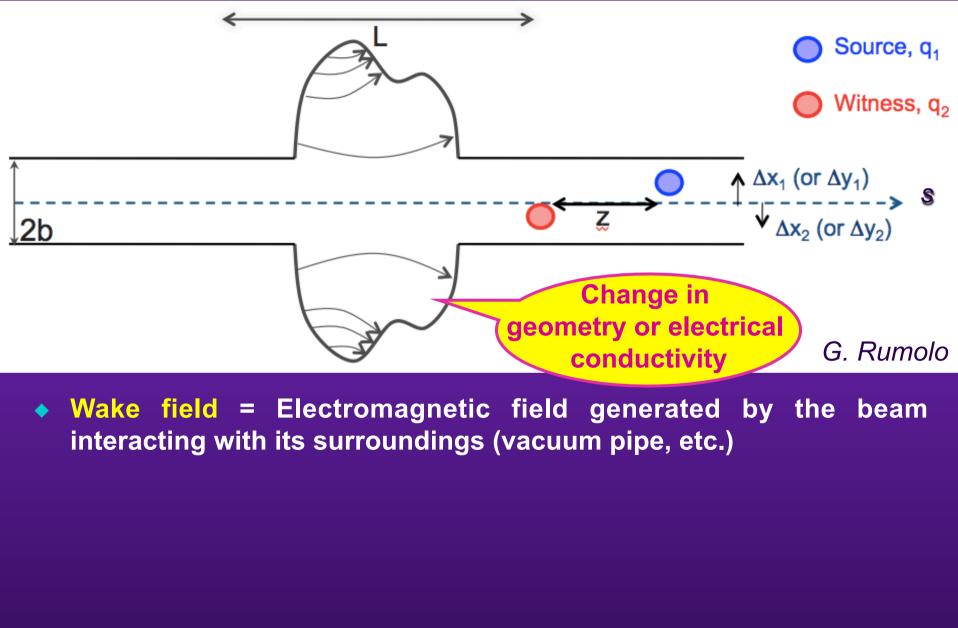
Pumping slots

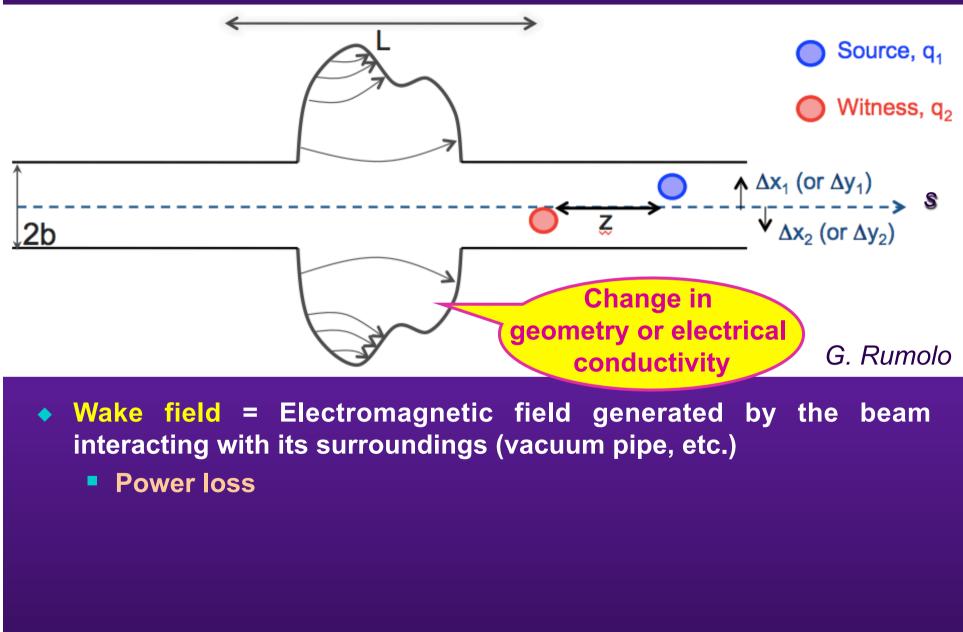


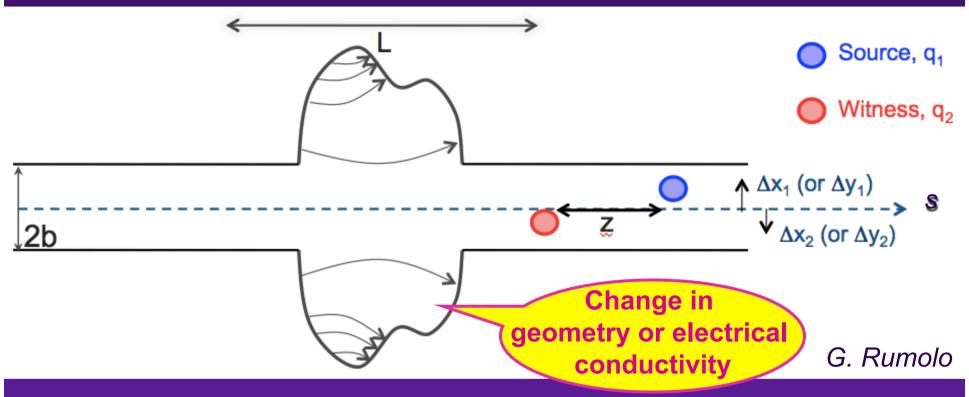




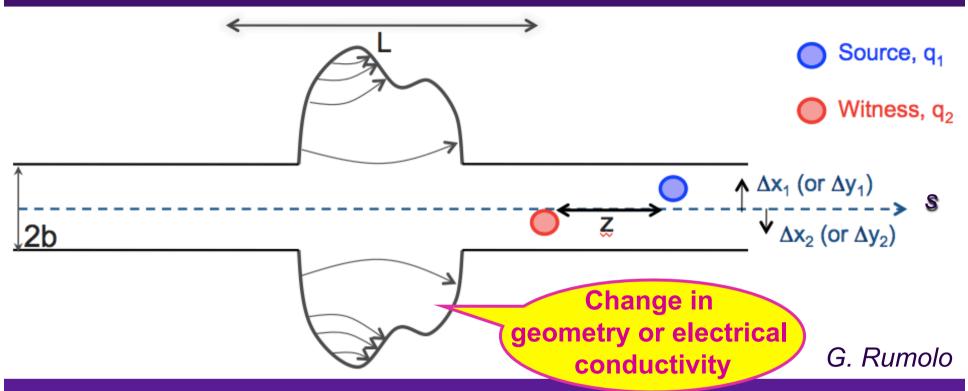








- Wake field = Electromagnetic field generated by the beam interacting with its surroundings (vacuum pipe, etc.)
 - Power loss
 - Beam instabilities



- Wake field = Electromagnetic field generated by the beam interacting with its surroundings (vacuum pipe, etc.)
 - Power loss
 - Beam instabilities
- Impedance = Fourier transform of the wake field (wake function)

2 fundamental approximations behind the "conventional impedances / wakes"

- 2 fundamental approximations behind the "conventional impedances / wakes"
 - Rigid-beam approximation => $z = s_{witness} s_{source} = Constant$

- 2 fundamental approximations behind the "conventional impedances / wakes"
 - Rigid-beam approximation =>

$$z = s_{witness} - s_{source} = Constant$$

Impulse approximation =>

$$v \Delta p = \int_{0}^{L} F \, ds$$
 Wake potential

Longitudinal wake

function

Longitudinal case

$$\int_{0}^{L} F_{l} ds = -e^{2} W_{l}(z)$$

Longitudinal case

$$\int_{0}^{L} F_{l} ds = -e^{2} W_{l}(z)$$

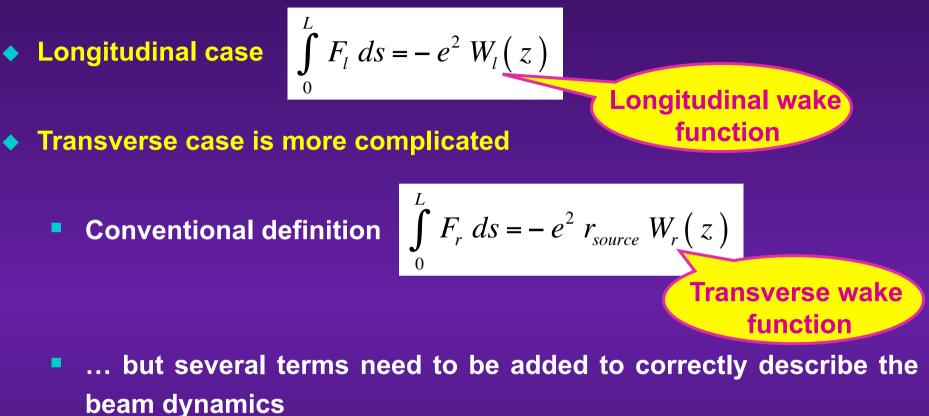
Longitudinal wake function

Transverse case is more complicated

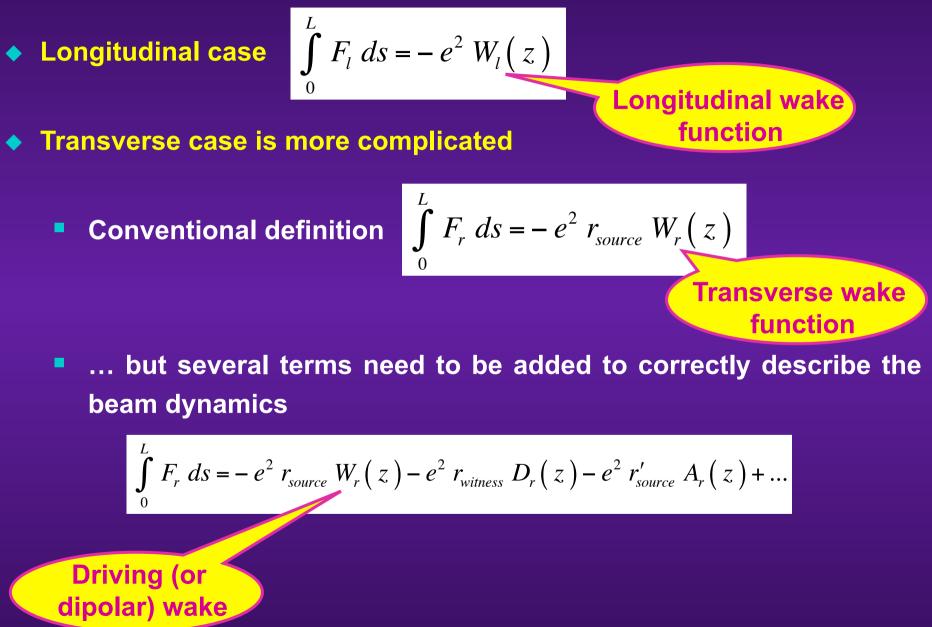
Conventional definition

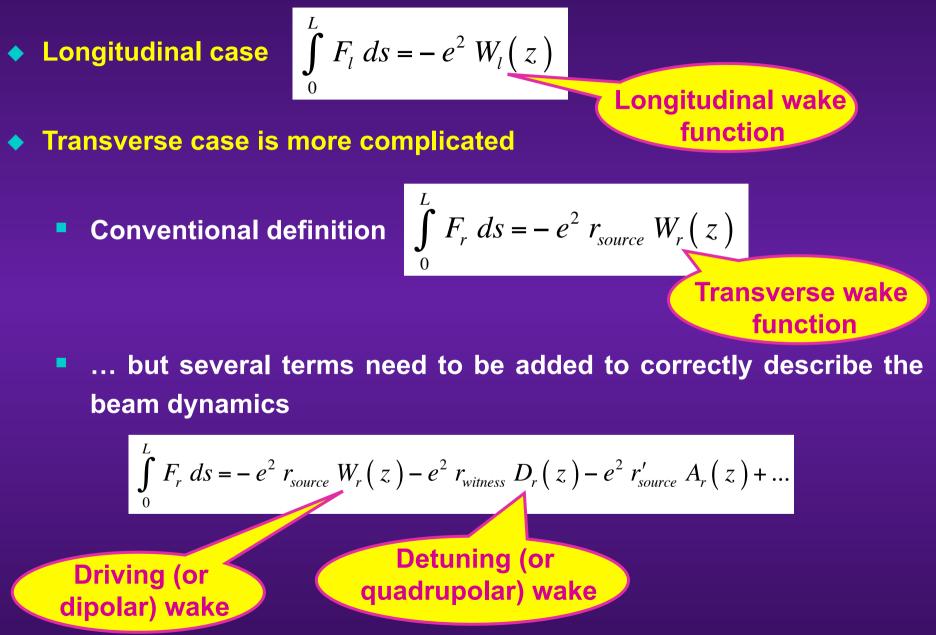
$$\int_{0}^{L} F_r \, ds = -e^2 \, r_{source} \, W_r(z)$$

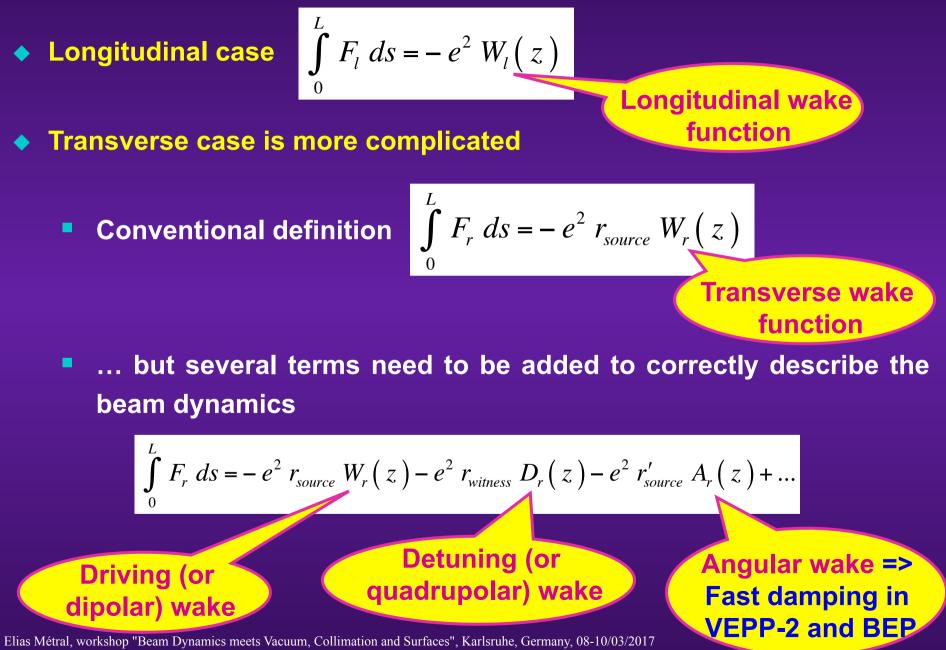
Transverse wake function



$$\int_{0}^{L} F_r ds = -e^2 r_{source} W_r(z) - e^2 r_{witness} D_r(z) - e^2 r_{source}' A_r(z) + \dots$$







- The impedance is a complex function of frequency and at least 5 contributions are needed to correctly characterized an equipment
 - Longitudinal impedance
 - Horizontal dipolar/driving impedance
 - Vertical dipolar/driving impedance
 - Horizontal quadrupolar/detuning impedance
 - Vertical quadrupolar/detuning impedance

In case of non axi-symmetric vacuum chambers (assuming that the particles are travelling at the speed of light => Assumption made in this talk)

CONTENTS

- Frequency range of interest
- Copper coating: why and which thickness?
- Effect of transverse damper
- Effects of other coatings (e.g. a-C) or surface treatments (e.g. LESS) to fight against e-cloud
- Effect of HTS coating
- Longitudinal weld
- Pumping slots
- Conclusions

a-C = amorphous carbonLESS = Laser treatment of the surfaceHTS = High Temperature Superconductor

Cut-off frequency (above which modes are propagating)

$$f_{cut-off}^{lowest}$$
 [GHz] $\approx \frac{10}{b \, [\text{cm}]}$

• N.A. for LHC: $b \approx 2 \text{ cm} \Rightarrow f_{cut-off} \approx 5 \text{ GHz}$

Cut-off frequency (above which modes are propagating)

$$f_{cut-off}^{lowest}$$
 [GHz] $\approx \frac{10}{b \, [\text{cm}]}$

• N.A. for LHC: $b \approx 2 \text{ cm} \Rightarrow f_{cut-off} \approx 5 \text{ GHz}$

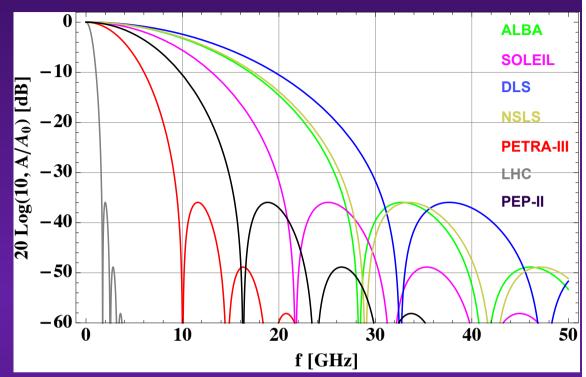
Lower limit => First Unstable (transverse) Betatron Line:

$$f_{FUBL} = (n - Q) f_{rev}$$

N.A. for LHC: (1 - 0.31) × 11245 ≈ 8 kHz

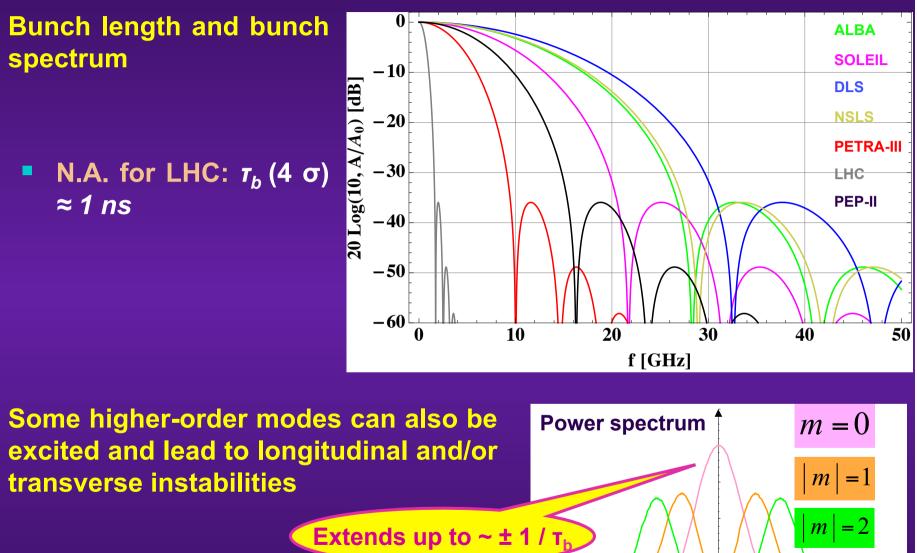
 Bunch length and bunch spectrum

N.A. for LHC: τ_b (4 σ)
 ≈ 1 ns



Bunch length and bunch spectrum

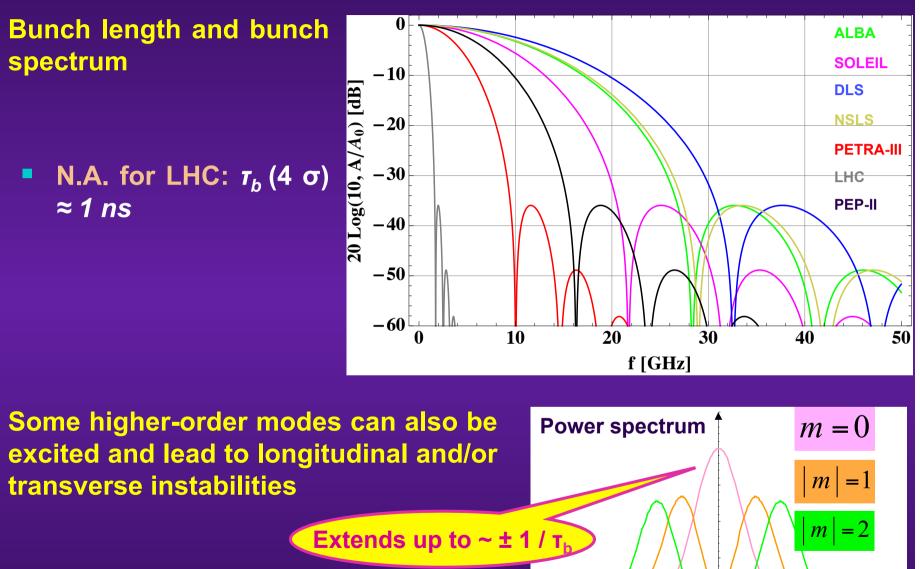
> • N.A. for LHC: τ_b (4 σ) ≈1 ns



Bunch length and bunch spectrum

> • N.A. for LHC: τ_b (4 σ) ≈1 ns

 \bullet



=> For LHC: from 8 kHz to few GHz

Keep the resistivity as low as possible for 3 reasons

- Keep the resistivity as low as possible for 3 reasons
 - Power loss => High-frequency

- Keep the resistivity as low as possible for 3 reasons
 - Power loss => High-frequency
 - Transverse Coupled-Bunch (Resistive-Wall) Instability: TCBI => Low-frequency

- Keep the resistivity as low as possible for 3 reasons
 - Power loss => High-frequency
 - Transverse Coupled-Bunch (Resistive-Wall) Instability: TCBI => Low-frequency
 - Transverse Mode-Coupling Instability: TMCI => High-frequency

• 1) Power loss => Due to real part of the longitudinal impedance

1) Power loss => Due to real part of the longitudinal impedance

$$P_{loss/m}^{G,RW,1layer} = \frac{1}{2 \pi R} \Gamma\left(\frac{3}{4}\right) \frac{M}{b} \left(\frac{N_b e}{2 \pi}\right)^2 \sqrt{\frac{c \rho Z_0}{2}} \sigma_t^{-3/2} \approx 101 \text{ mW/m}$$

$$\Gamma\left(\frac{3}{4}\right) = 1.23$$
Euler gamma function

$$M = 2808$$

$$N_b = 1.15 \times 10^{11} \text{ p/b}$$

$$\sigma_t = 0.25 \text{ ns}$$
LHC circumference = L

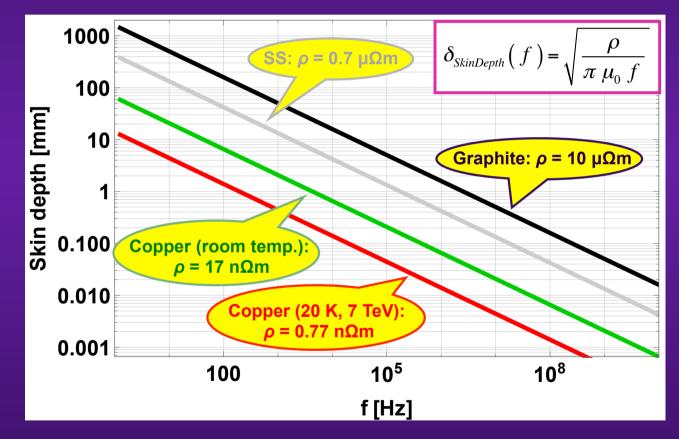
$$= 2 \pi R = 26658.883 \text{ m}$$

$$\rho_{Cu}^{20K,7\text{TeV}} = 7.7 \times 10^{-10} \Omega \text{m}$$

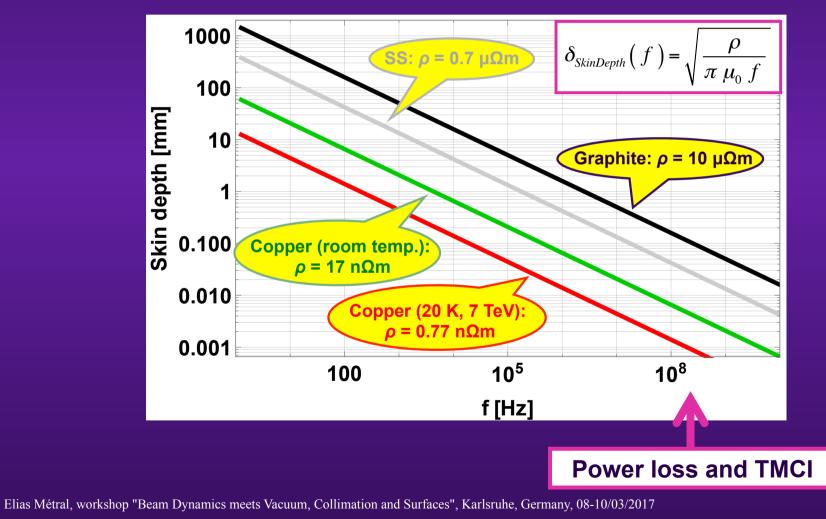
b = beam screen half height = 36.8 / 2 = 18.4 \text{ mm}

- 1) Power loss => Due to real part of the longitudinal impedance
 - For SS for instance, the power loss would be ~ 30 times more
 - Thickness of Cu (20 K, 7 TeV) coating => 1 (few) µm enough

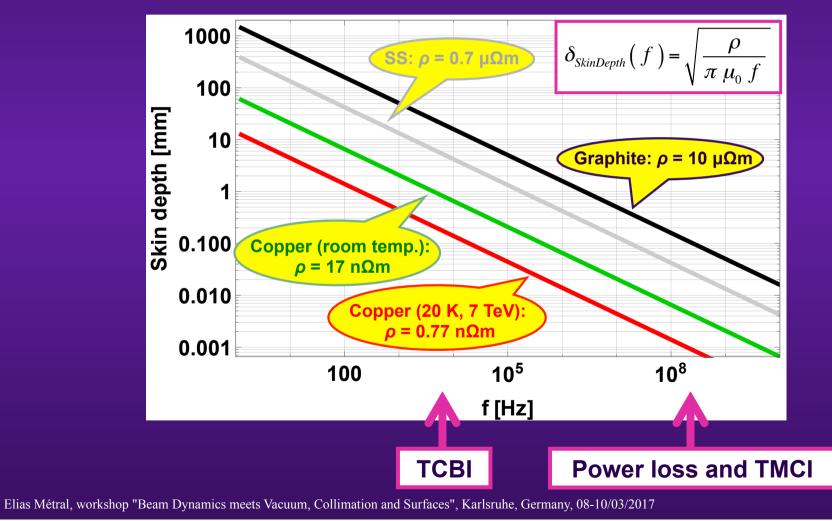
- 1) Power loss => Due to real part of the longitudinal impedance
 - For SS for instance, the power loss would be ~ 30 times more
 - Thickness of Cu (20 K, 7 TeV) coating => 1 (few) µm enough



- 1) Power loss => Due to real part of the longitudinal impedance
 - For SS for instance, the power loss would be ~ 30 times more
 - Thickness of Cu (20 K, 7 TeV) coating => 1 (few) µm enough



- 1) Power loss => Due to real part of the longitudinal impedance
 - For SS for instance, the power loss would be ~ 30 times more
 - Thickness of Cu (20 K, 7 TeV) coating => 1 (few) µm enough



◆ 2) TCBI => Due to real part of the transverse impedance

◆ 2) TCBI => Due to real part of the transverse impedance

$$\tau_{y} \approx \frac{\gamma Q_{y} \mu_{0}}{M N_{b} r_{p} \operatorname{Re} \left[\frac{Z_{y} (2 \pi f_{FUBL})}{2 \pi R}\right]}$$

Instability rise-time (in the thick-wall regime)

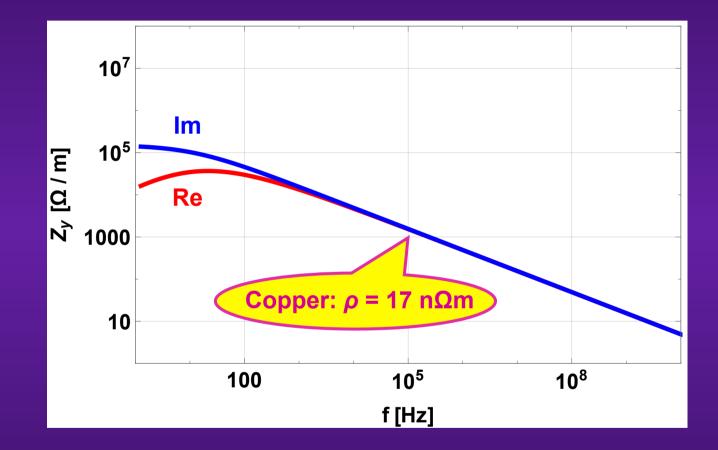
◆ 2) TCBI => Due to real part of the transverse impedance

$$\tau_{y} \approx \frac{\gamma Q_{y} \mu_{0}}{M N_{b} r_{p} \operatorname{Re} \left[\frac{Z_{y} (2 \pi f_{FUBL})}{2 \pi R}\right]}$$

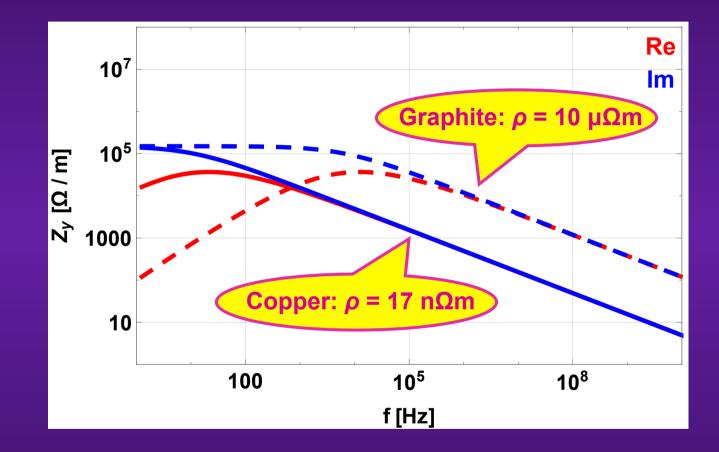
Instability rise-time (in the thick-wall regime)

- Previous plot reveals why in this case few tens / hundreds of µm are needed (at low frequency, IF we are in the thick-wall regime)
- This thick-wall regime is for instance not the case with the LHC collimators...

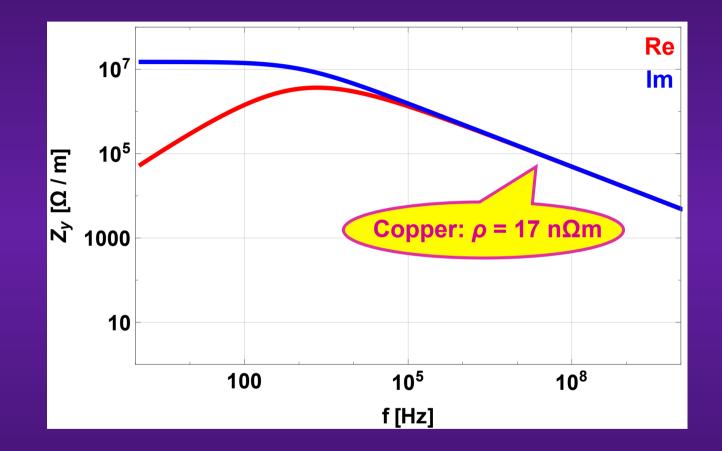
LHC beam pipe: round, 20 mm radius, 1 m long



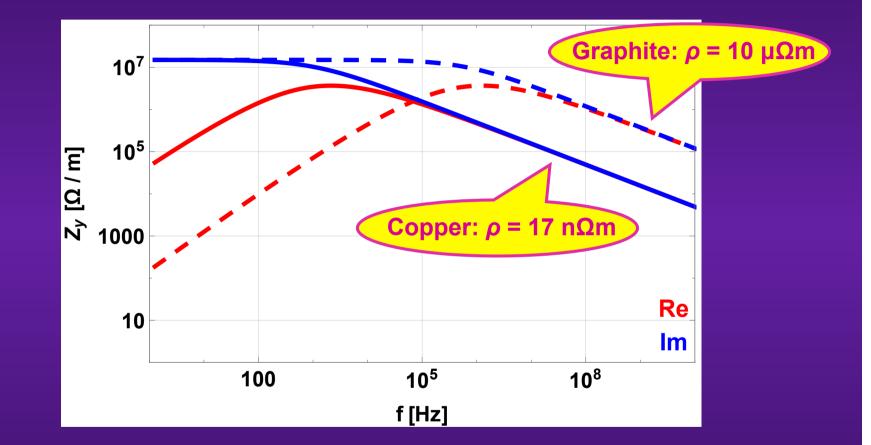
LHC beam pipe: round, 20 mm radius, 1 m long

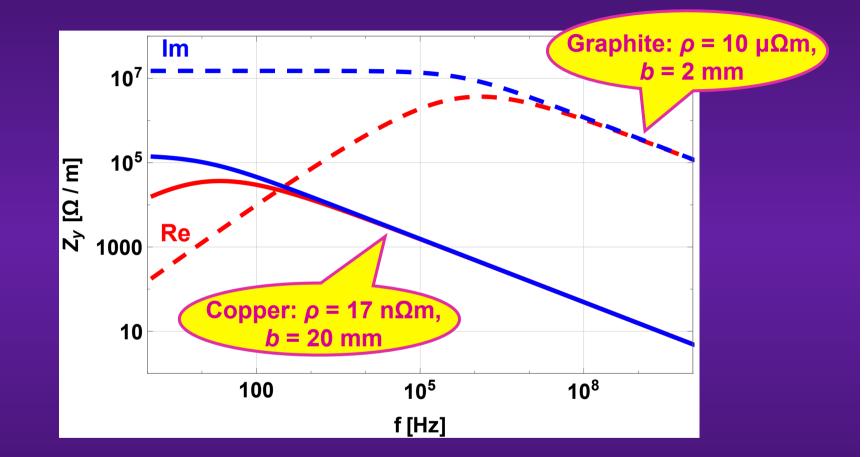


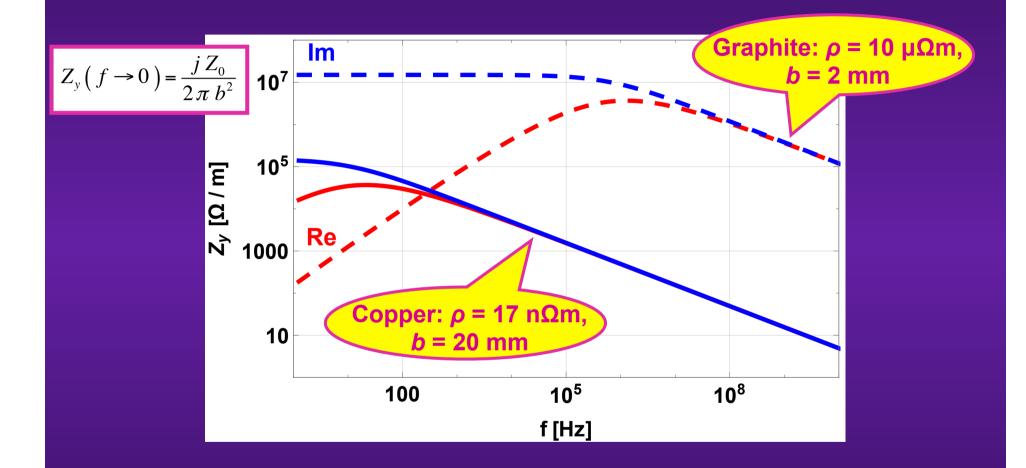
LHC beam pipe: round, 2 mm radius, 1 m long

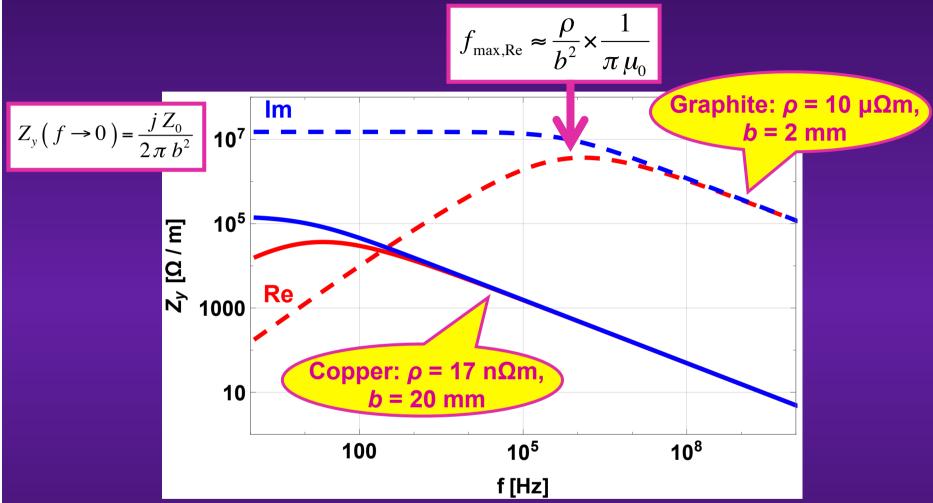


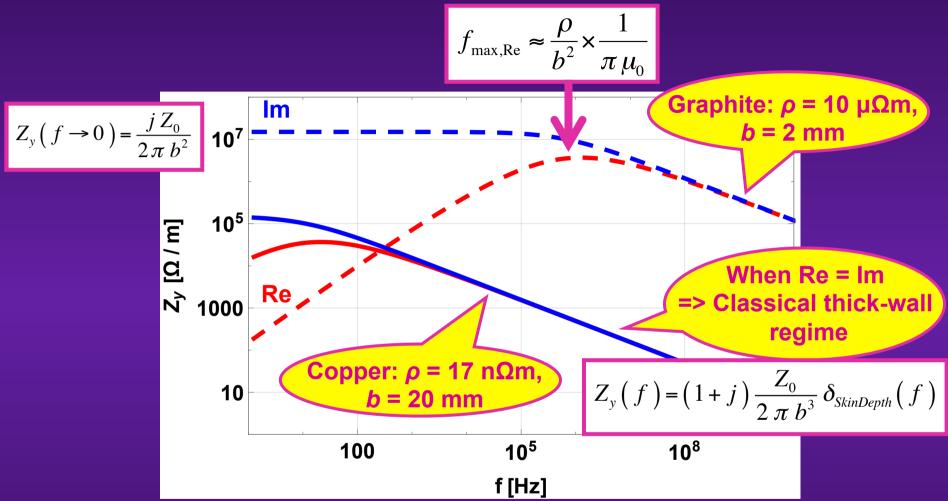
LHC beam pipe: round, 2 mm radius, 1 m long



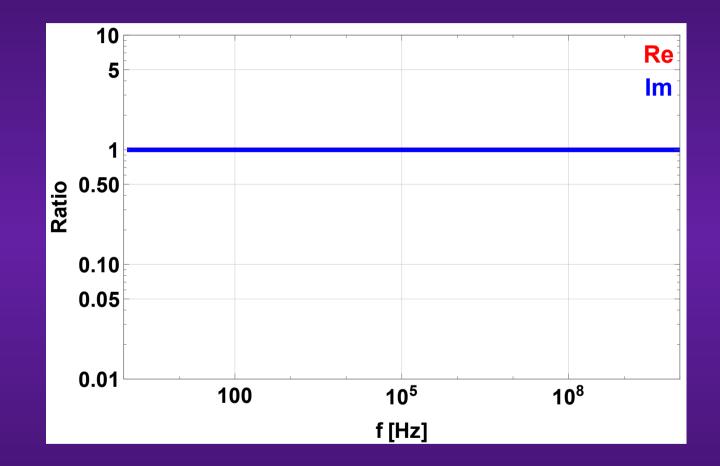




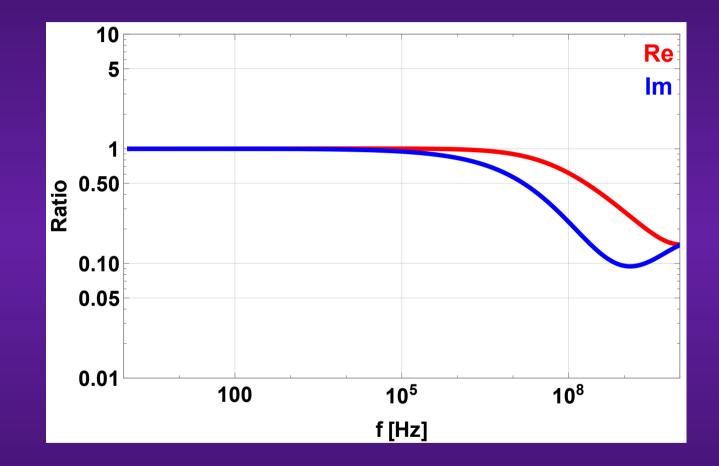




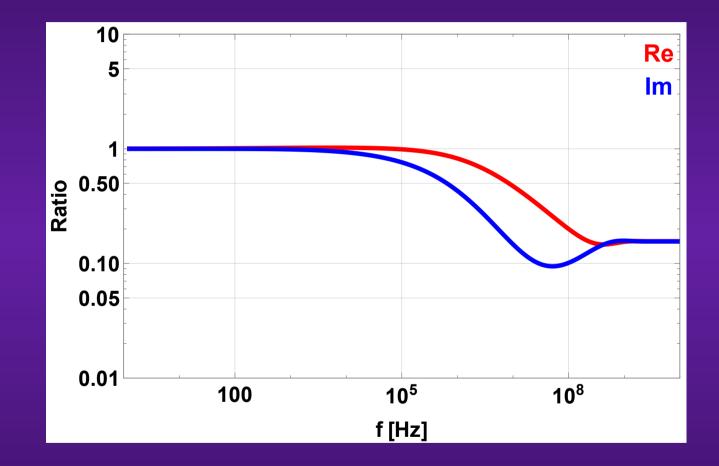
SS beam pipe with 20 mm radius and 0 µm copper coating (room temp.)



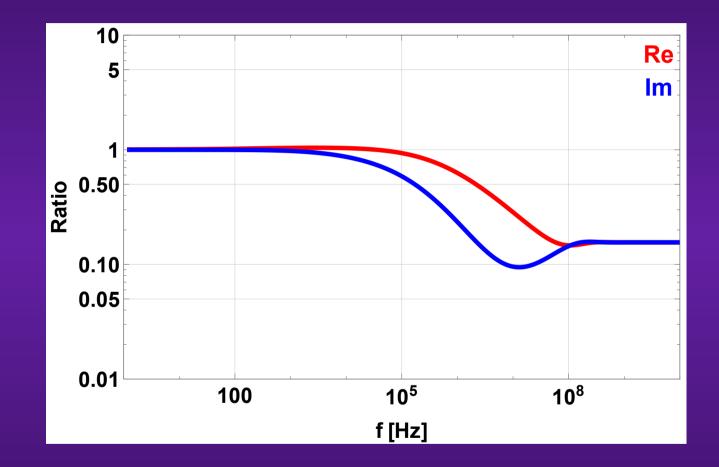
SS beam pipe with 20 mm radius and 1 µm copper coating (room temp.)



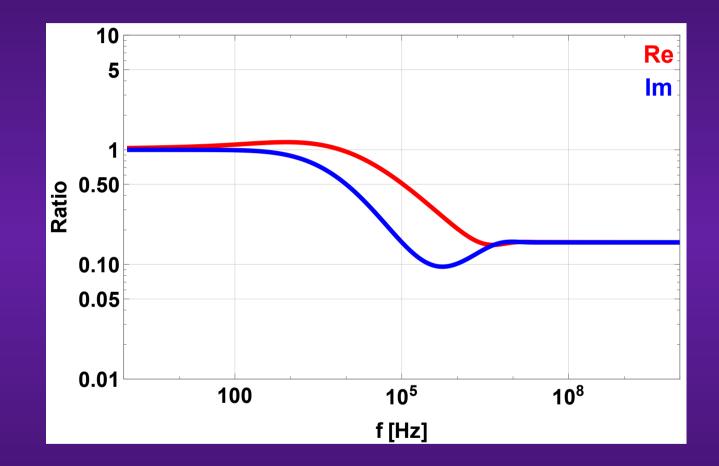
SS beam pipe with 20 mm radius and 5 µm copper coating (room temp.)



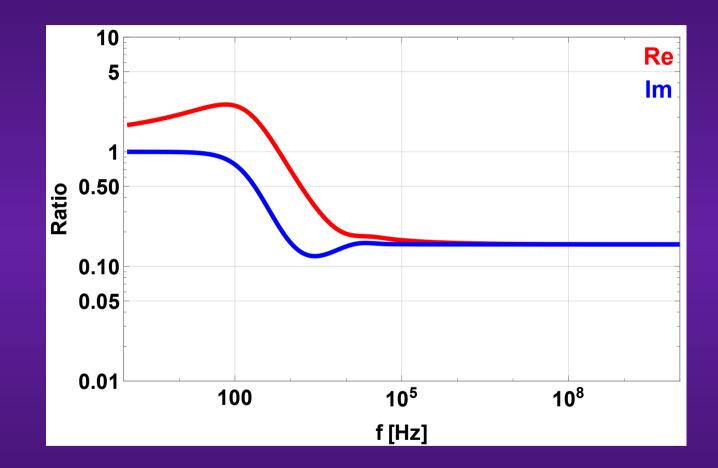
SS beam pipe with 20 mm radius and 10 µm copper coating (room temp.)



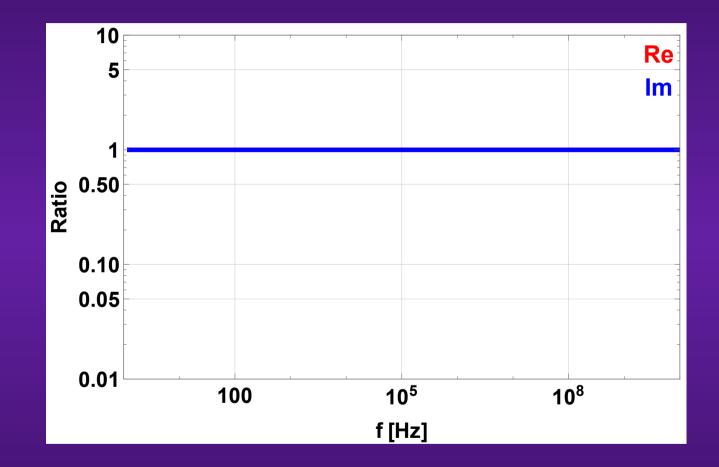
SS beam pipe with 20 mm radius and 50 µm copper coating (room temp.)



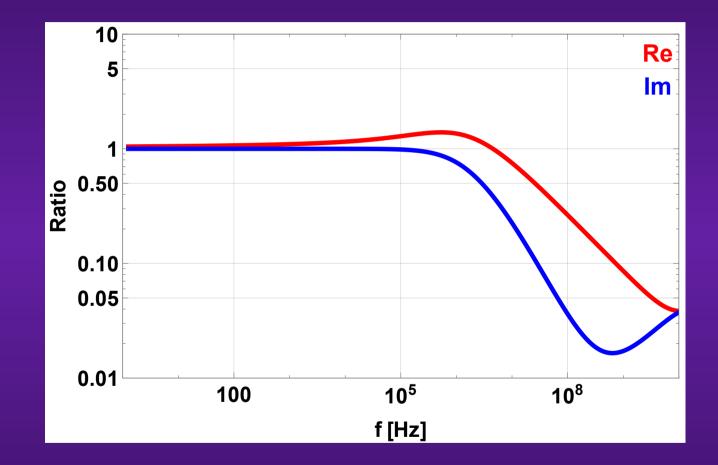
SS beam pipe with 20 mm radius and 1000 µm = 1 mm copper coating (room temp.)



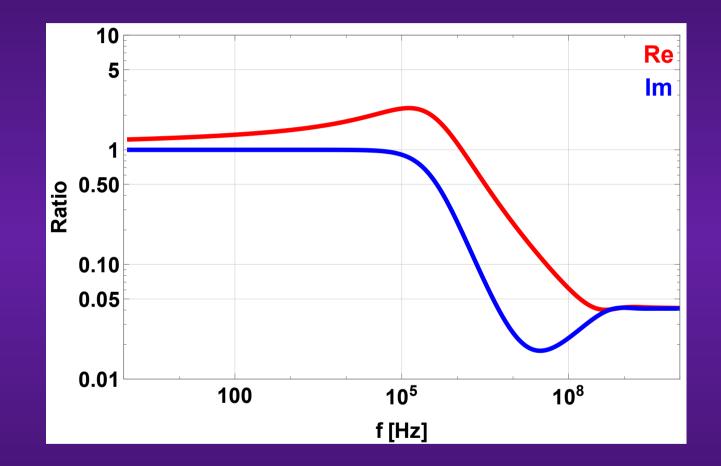
Graphite beam pipe with 2 mm radius and 0 µm copper coating (room temp.)



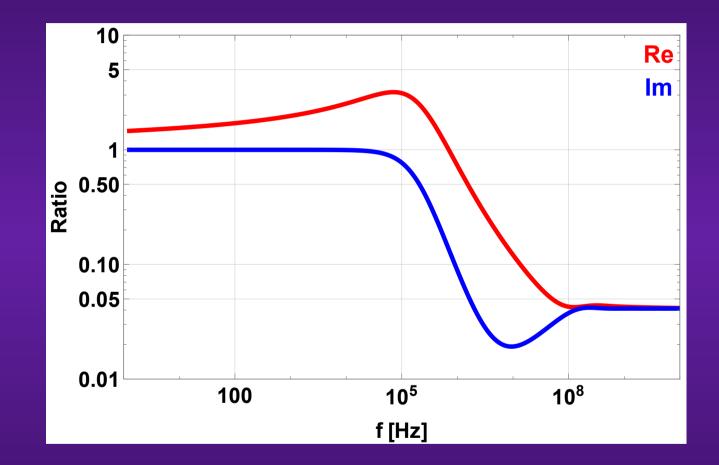
Graphite beam pipe with 2 mm radius and 1 µm copper coating (room temp.)



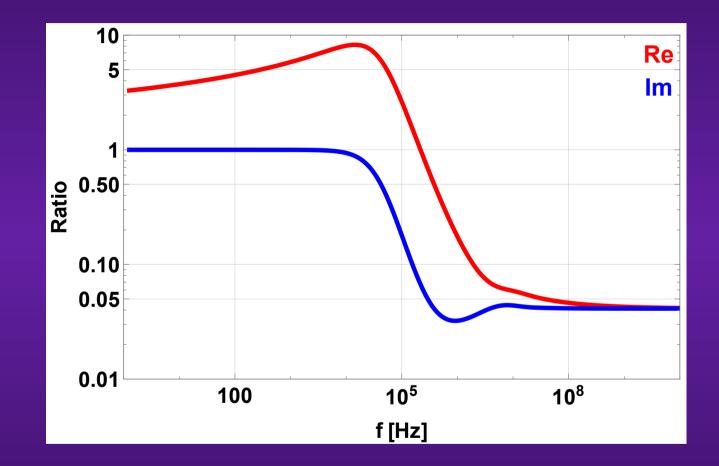
Graphite beam pipe with 2 mm radius and 5 µm copper coating (room temp.)



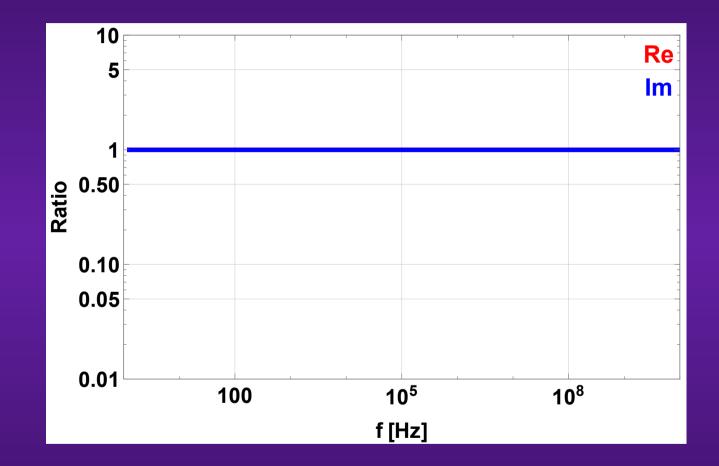
Graphite beam pipe with 2 mm radius and 10 µm copper coating (room temp.)



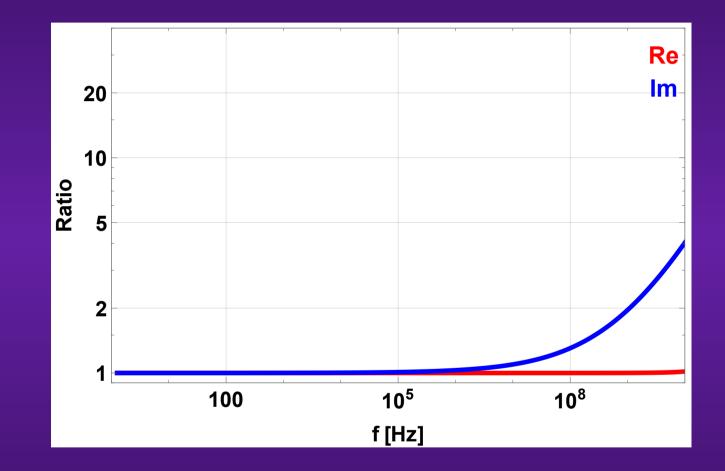
Graphite beam pipe with 2 mm radius and 50 µm copper coating (room temp.)



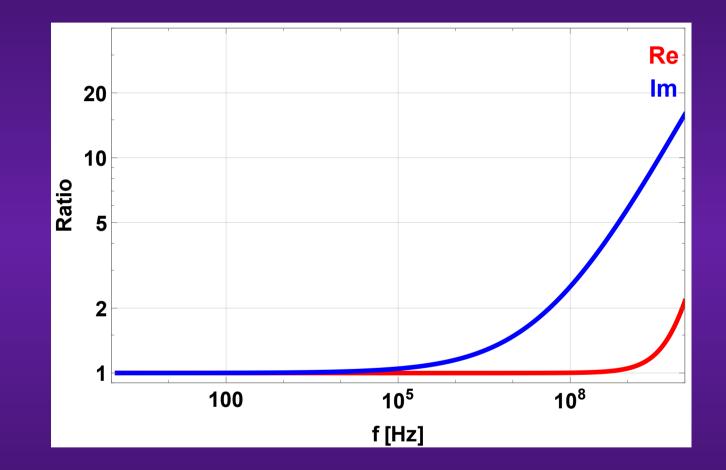
Copper (room temp.) beam pipe with 20 mm radius and 0 µm graphite coating



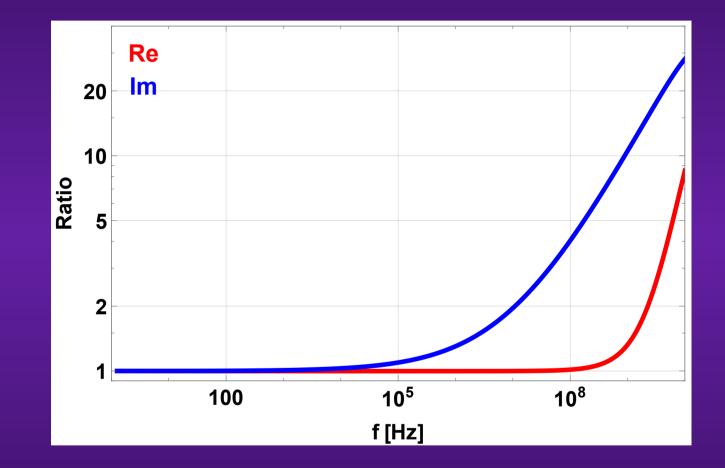
Copper (room temp.) beam pipe with 20 mm radius and 1 µm graphite coating



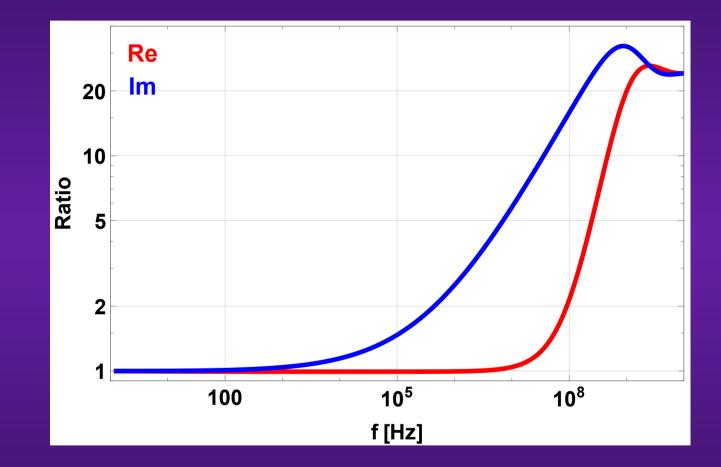
Copper (room temp.) beam pipe with 20 mm radius and 5 µm graphite coating



Copper (room temp.) beam pipe with 20 mm radius and 10 µm graphite coating

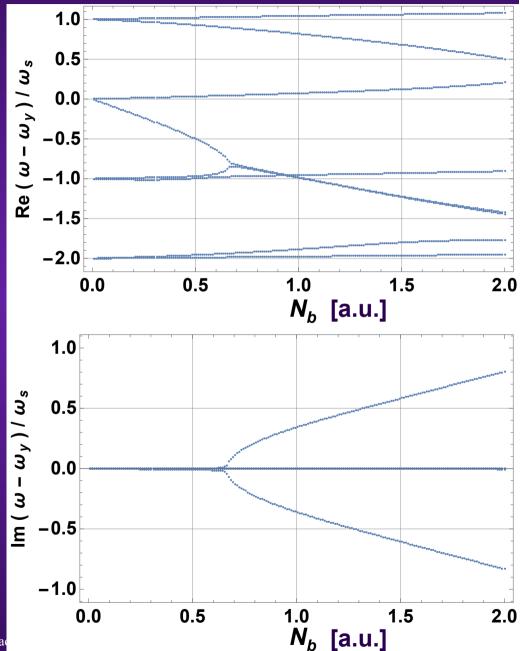


Copper (room temp.) beam pipe with 20 mm radius and 50 µm graphite coating



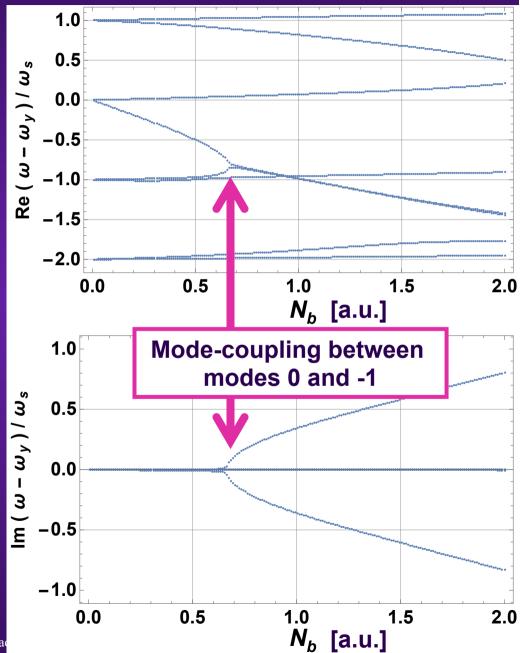
 3) TMCI => (Mainly) due to imaginary part of the transverse impedance

- 3) TMCI => (Mainly) due to imaginary part of the transverse impedance
 - Example case (~ LHC)



Elias Métral, workshop "Beam Dynamics meets Vacuum, Collimation and Surfac

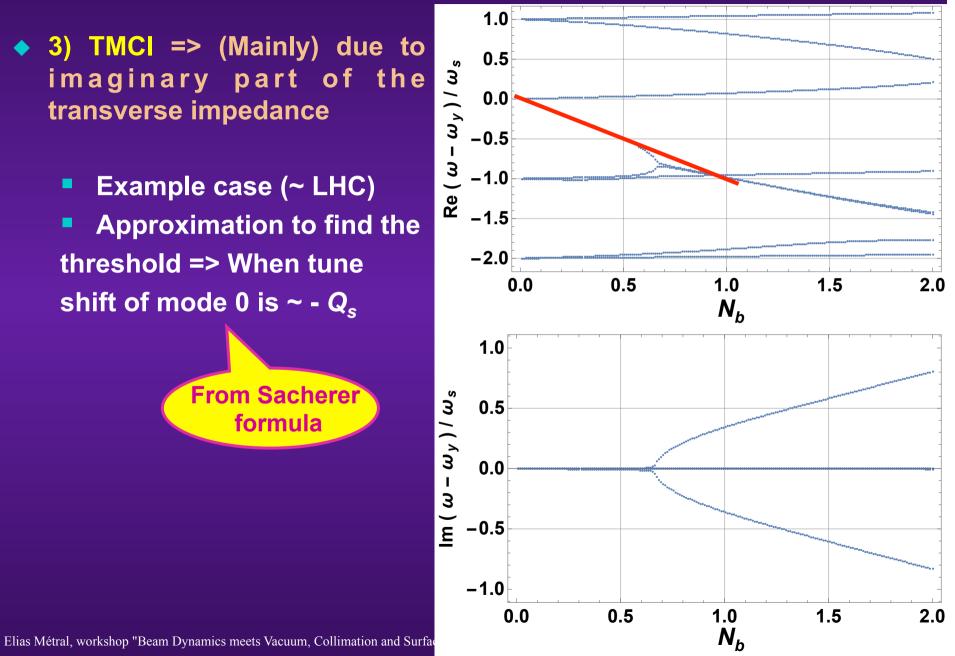
- 3) TMCI => (Mainly) due to imaginary part of the transverse impedance
 - Example case (~ LHC)



Elias Métral, workshop "Beam Dynamics meets Vacuum, Collimation and Surfa

- ♦ 3) TMCI => (Mainly) due to imaginary part of the transverse impedance
 - Example case (~ LHC)
 - Approximation to find the threshold => When tune shift of mode 0 is $\sim - Q_s$





- 3) TMCI => (Mainly) due to imaginary part of the transverse impedance
 - Example case (~ LHC)
 - Approximation to find the threshold => When tune shift of mode 0 is ~ - Q_s

Weighted by the bunch spectrum (mode 0), which also depends on bunch length…

= 2E - 3

 $\approx 134 \text{ M}\Omega/\text{m}$ $= R/Q_v = 71.5 \text{ m}$

 $\tau_b = 1 \text{ ns}$

 $4 \pi \left(E_t / e \right) \tau_b Q_s$

 $\overline{N}_{h} e \beta_{v}^{av}$

= 7E12

 $\operatorname{Im}\left(Z_{v}^{eff}\right) < \operatorname{Im}\left(Z_{v}^{eff}\right)_{ma}$

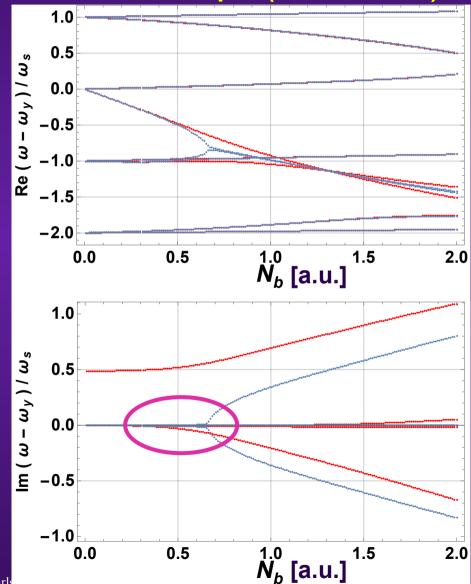
1.15E11 p/b

 A (bunch by bunch) resistive transverse damper is usually used to damp the TCBI => IF instability rise-time is longer than ~ 10 turns

- A (bunch by bunch) resistive transverse damper is usually used to damp the TCBI => IF instability rise-time is longer than ~ 10 turns
- Depending on Q' (chromaticity) and the transverse damper gain, a certain amount of non-linearities (Landau octupoles) is also needed to stabilize the single-bunch instabilities by Landau damping

- A (bunch by bunch) resistive transverse damper is usually used to damp the TCBI => IF instability rise-time is longer than ~ 10 turns
- Depending on Q' (chromaticity) and the transverse damper gain, a certain amount of non-linearities (Landau octupoles) is also needed to stabilize the single-bunch instabilities by Landau damping
- Recent studies revealed that for Q' = 0 the resistive transverse damper is destabilising (for the single bunch) and shed a light on the physical mechanism

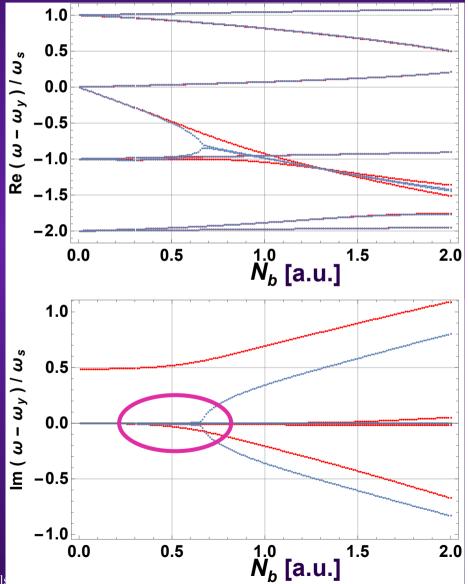
Destabilising effect of the resistive transverse damper (in red below)



Elias Métral, workshop "Beam Dynamics meets Vacuum, Collimation and Surfaces", Karls

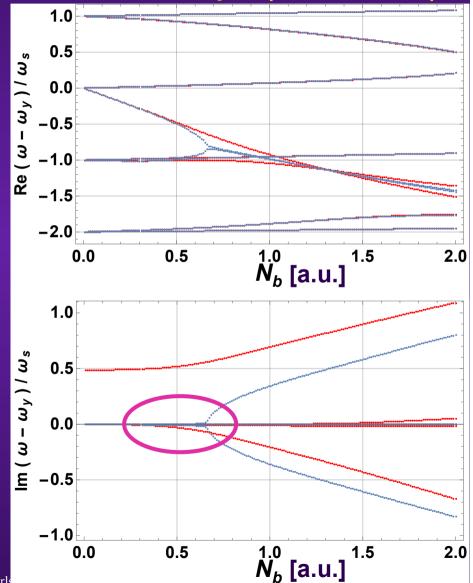
Destabilising effect of the resistive transverse damper (in red below)

 This is the interaction between modes - 1 and 0 through the damper which creates the instability



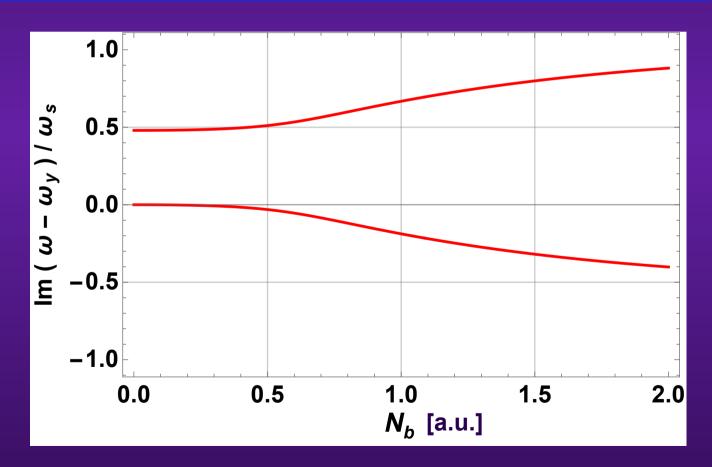
Destabilising effect of the resistive transverse damper (in red below)

- This is the interaction between modes - 1 and 0 through the damper which creates the instability
- The "coupling" between the 2 modes pushes apart the instability growth rates and as the lowest one is 0, it becomes negative

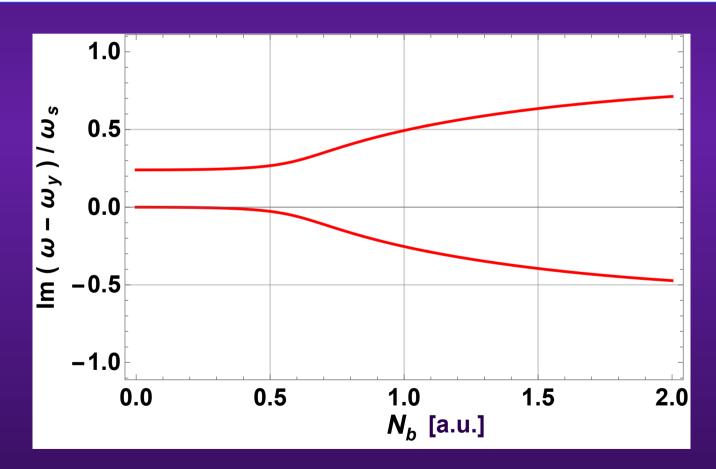


Considering only the 2 modes 0 and - 1 yields

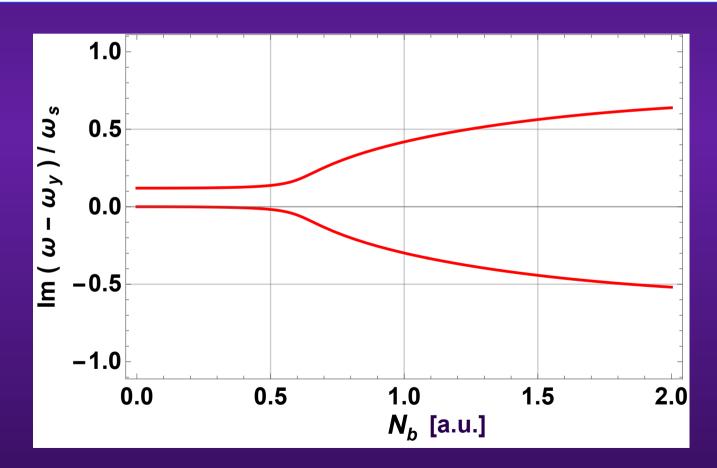
With the transverse damper gain used before



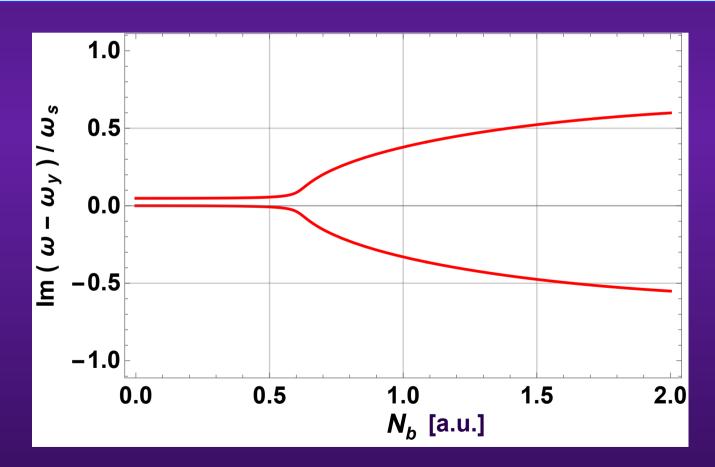
With the transverse damper gain used before / 2



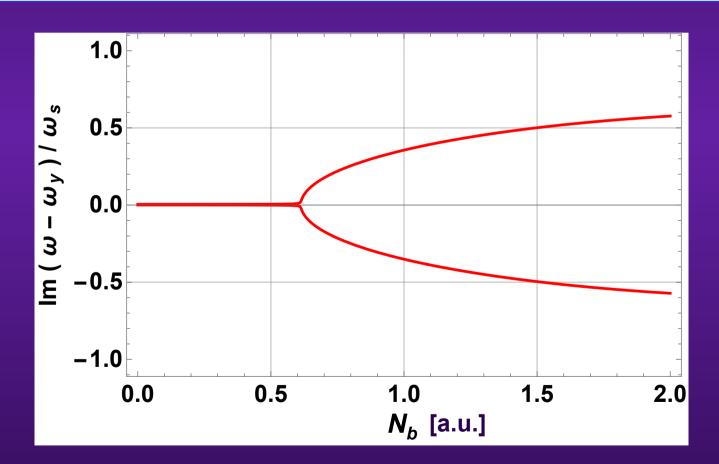
With the transverse damper gain used before / 4



With the transverse damper gain used before / 10



With the transverse damper gain used before / 100



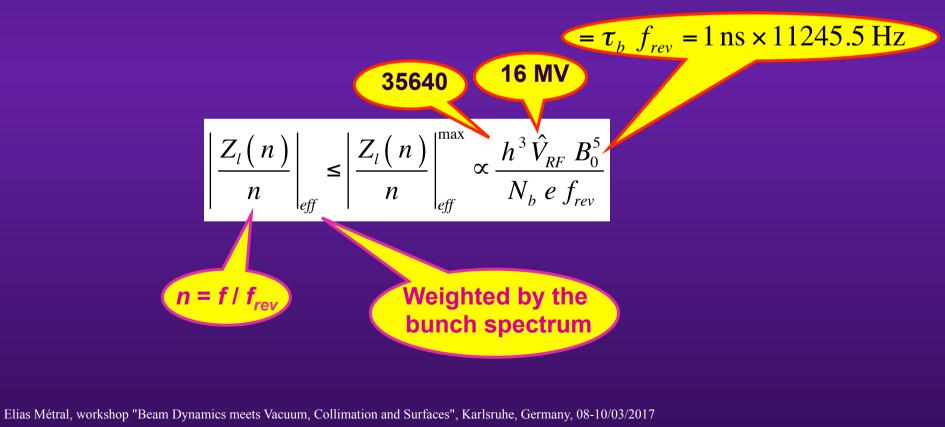
 The consequences on the Landau damping are currently under investigation (as the assumption of independent modes cannot be made anymore)

- The consequences on the Landau damping are currently under investigation (as the assumption of independent modes cannot be made anymore)
- However, with a sufficiently strong (and low noise) transverse damper, the TCBI (low frequency) should not be a problem anymore => Particular attention should be paid to the high frequency (singlebunch) regime

 This will increase the resistivity (or roughness) at high frequency => Mainly the imaginary parts of the longitudinal and transverse impedances

- This will increase the resistivity (or roughness) at high frequency => Mainly the imaginary parts of the longitudinal and transverse impedances
 - Increase of imaginary part of longitudinal impedance at high frequency => More critical for the loss of longitudinal Landau damping

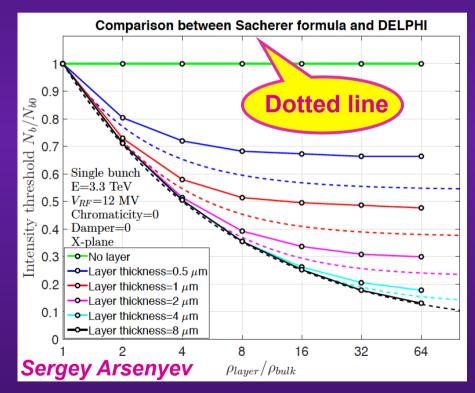
- This will increase the resistivity (or roughness) at high frequency => Mainly the imaginary parts of the longitudinal and transverse impedances
 - Increase of imaginary part of longitudinal impedance at high frequency => More critical for the loss of longitudinal Landau damping



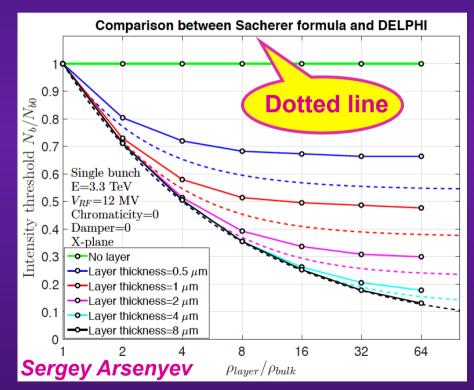
Increase of imaginary part of transverse impedance at high frequency => More critical for TMCI

- Increase of imaginary part of transverse impedance at high frequency => More critical for TMCI
 - Example case of FCC-hh, where laser treatment was proposed as baseline for SEY reduction

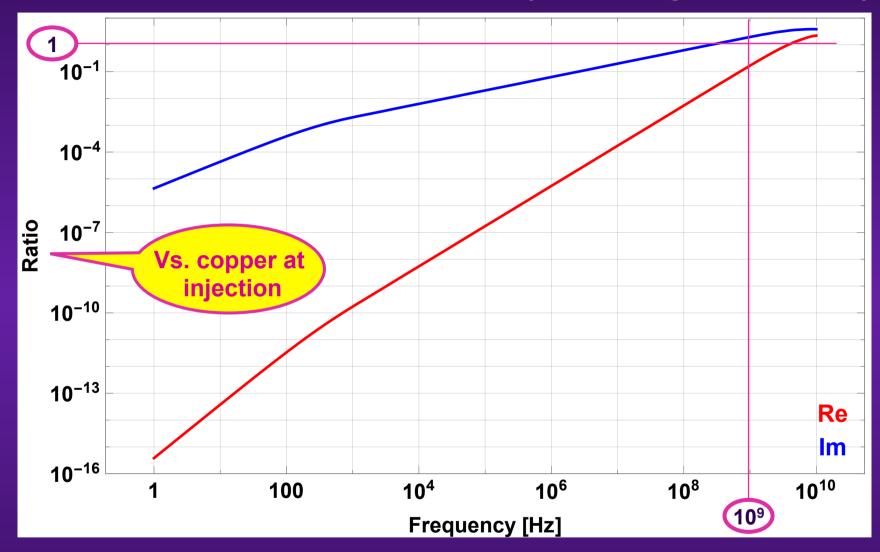
- Increase of imaginary part of transverse impedance at high frequency => More critical for TMCI
 - Example case of FCC-hh, where laser treatment was proposed as baseline for SEY reduction

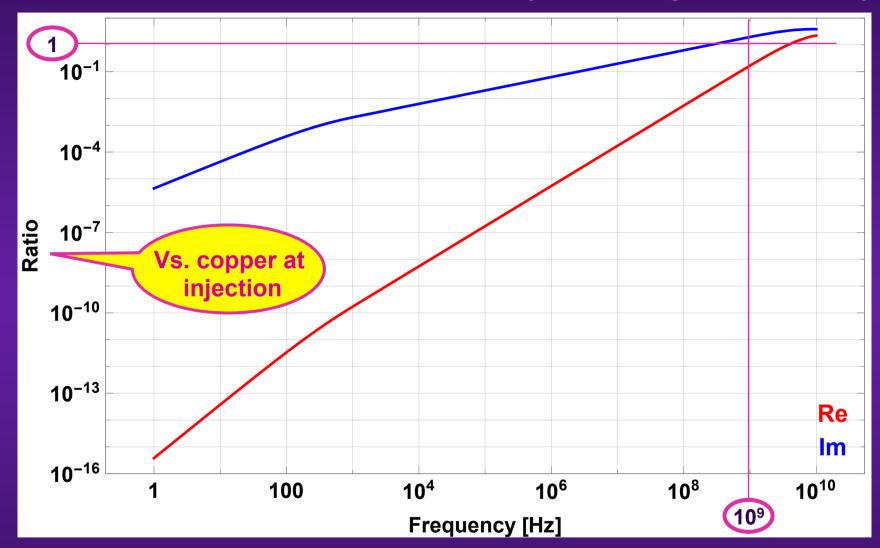


- Increase of imaginary part of transverse impedance at high frequency => More critical for TMCI
 - Example case of FCC-hh, where laser treatment was proposed as baseline for SEY reduction

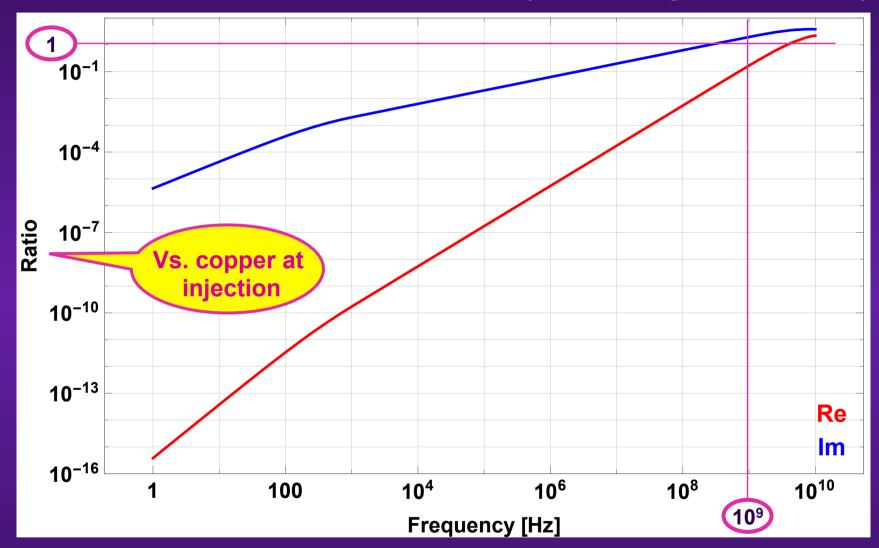


=> Measurements at low temperature and high magnetic field are required (and planned)

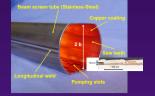


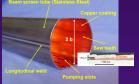


Much better at low and intermediate frequencies

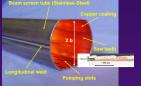


- Much better at low and intermediate frequencies
- Pay attention to higher frequencies as it could impact TMCI

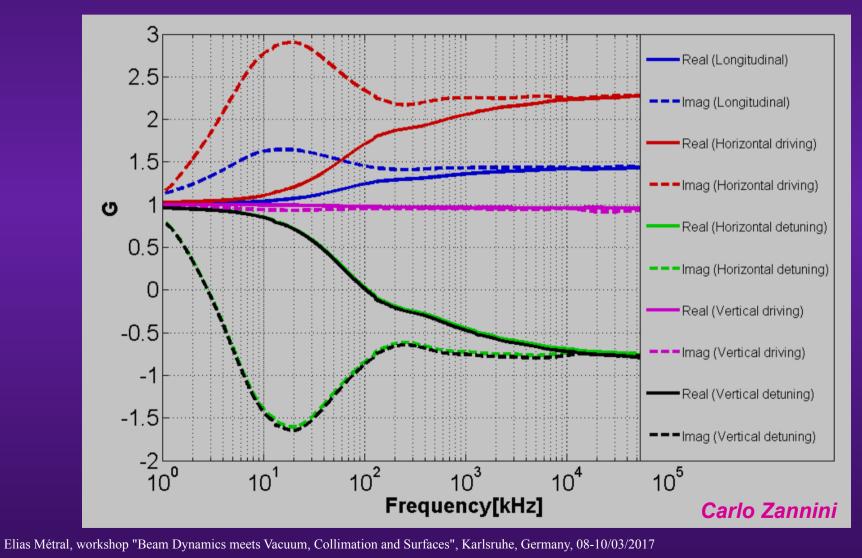




 Increased factor deduced from 3D CST simulations with 50 µm of copper on top of SS and assuming a 2 mm high weld in SS



 Increased factor deduced from 3D CST simulations with 50 µm of copper on top of SS and assuming a 2 mm high weld in SS



• Effect on the power loss

• Effect on the power loss

$$\rho_{Cu}^{20K,7\text{TeV}} = 7.7 \times 10^{-10} \,\Omega\text{m}$$
$$\rho_{SS}^{20K} = 6 \times 10^{-7} \,\Omega\text{m}$$

$$\frac{\Delta_l^{Weld}}{2 \pi b} = \frac{2}{2 \pi \times 18.4} = \frac{1}{\pi \times 18.4} \approx \frac{1}{60}$$

=>

$$\frac{P_{loss/m}^{Weld}}{P_{loss/m}^{G,RW,1\,\text{layer}}} \approx \sqrt{\frac{\rho_{SS}^{20\,K}}{\rho_{Cu}^{20\,K}}} \times \frac{\Delta_l^{Weld}}{2\,\pi\,b} \approx 48\%$$

Effect on the power loss

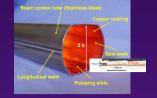
=>

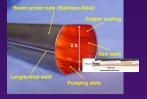
$$\rho_{Cu}^{20K,7\text{TeV}} = 7.7 \times 10^{-10} \,\Omega\text{m}$$
$$\rho_{SS}^{20K} = 6 \times 10^{-7} \,\Omega\text{m}$$

$$\frac{\Delta_l^{Weld}}{2 \pi b} = \frac{2}{2 \pi \times 18.4} = \frac{1}{\pi \times 18.4} \approx \frac{1}{60}$$

$$\frac{P_{loss/m}^{Weld}}{P_{loss/m}^{G,RW,11ayer}} \approx \sqrt{\frac{\rho_{SS}^{20K}}{\rho_{Cu}^{20K}}} \times \frac{\Delta_l^{Weld}}{2\pi b} \approx 48\%$$

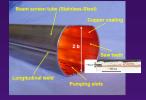
=> The estimated increase of the power loss by ~ 50% is in agreement with the previous simulations (high frequency effect)





Fraction of surface covered by the holes

- In the arcs: η = 4.0%
- In the LSS: η = 1.8% to 2.6% (depends on screen Φ)



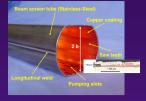
by the holes

Fraction of surface covered by the holes

- In the arcs: η = 4.0%
- In the LSS: η = 1.8% to 2.6% (depends on screen ϕ)
- This will mainly increase the imaginary part of the longitudinal and transverse impedances (=> TMCI)
 Total length covered

 $Z_y \propto j \frac{\eta L}{r^2}$

$$\frac{Z_l(n)}{n} \propto j \frac{\eta L}{b}$$



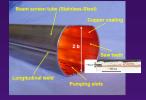
by the holes

Fraction of surface covered by the holes

- In the arcs: η = 4.0%
- In the LSS: η = 1.8% to 2.6% (depends on screen Φ)
- This will mainly increase the imaginary part of the longitudinal and transverse impedances (=> TMCI)
 Total length covered

$$\frac{Z_l(n)}{n} \propto j \frac{\eta L}{b} \qquad \qquad Z_y \propto j \frac{\eta L}{b^3}$$

Recommendations => Minimize the numerator and maximize the denominator... + Optimize the shape of the slots to minimize the perturbation of the induced current: elongated and rounded



Fraction of surface covered by the holes

- In the arcs: η = 4.0%
- In the LSS: η = 1.8% to 2.6% (depends on screen Φ)

 $\frac{Z_l(n)}{d} \propto j \frac{\eta L}{d}$

 This will mainly increase the imaginary part of the longitudinal and transverse impedances (=> TMCI)

by the holes
$$Z_y \propto j \frac{\eta L}{h^3}$$

- Recommendations => Minimize the numerator and maximize the denominator... + Optimize the shape of the slots to minimize the perturbation of the induced current: elongated and rounded
- In addition, some trapped modes could be created => Randomization of the slots lengths (between 6,7,8,9,10 mm with average at 8 mm) + randomization of the slot spacing



 Impact of impedance effects on beam chamber specification is relatively well understood

- Impact of impedance effects on beam chamber specification is relatively well understood
- Next challenges might come from the correct characterization (vs. frequency) of some coatings or surface treatment

- Impact of impedance effects on beam chamber specification is relatively well understood
- Next challenges might come from the correct characterization (vs. frequency) of some coatings or surface treatment
- The transitions between the beam pipes and any equipment should also be optimized (to be as smooth as possible => Famous 15 deg for LHC but depends on the particular case), as well as robust designs when RF fingers are involved (for longitudinal and/or transverse displacements)

- Impact of impedance effects on beam chamber specification is relatively well understood
- Next challenges might come from the correct characterization (vs. frequency) of some coatings or surface treatment
- The transitions between the beam pipes and any equipment should also be optimized (to be as smooth as possible => Famous 15 deg for LHC but depends on the particular case), as well as robust designs when RF fingers are involved (for longitudinal and/or transverse displacements)

Example of RF fingers: PIMs = Plug-In Modules



Many thanks for your attention!

APPENDIX A: LHC BEAM SCREENS

Arc beam screens:

Inner dimension between flats:	36.8 mm
Inner dimension between radii:	46.4 mm
SS thickness:	1.0 mm
Cu thickness:	0.075 mm

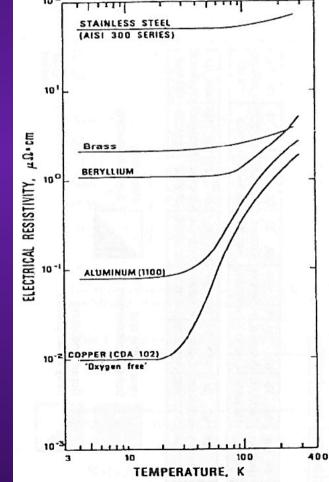
LSS beam screens:

Inner dimension between flats:	varying from 37.6 until 6	61.0 mm
Inner dimension between radii:	varying from 47.2 until 70.7 mm	
SS thickness:	0.6 mm	
Cu thickness:	0.075 mm	Courtesy of N. Kos

Resistance SS at room temp: 7E-7 ohm.m		
RRR SS:	1.2	
Low temp resistance SS:	7E-7/1.2 = 6E-7 ohm.m	
Resistance copper at room temp:	2E-8 ohm.m	
RRR Cu (co-laminated surface):	100	
Low temp Cu resistance:	2E-8/100 = 2E-10 ohm.m Courtesy of N. Kos	

APPENDIX B: RRR (Residual Resistivity Ratio)

Reduction of the resistivity with temperature => The resistivity decreases with temperature towards a minimum (determined by purity) and the RRR is defined as the ratio of the DC resistivity at room temperature to its cold-DC lower limit



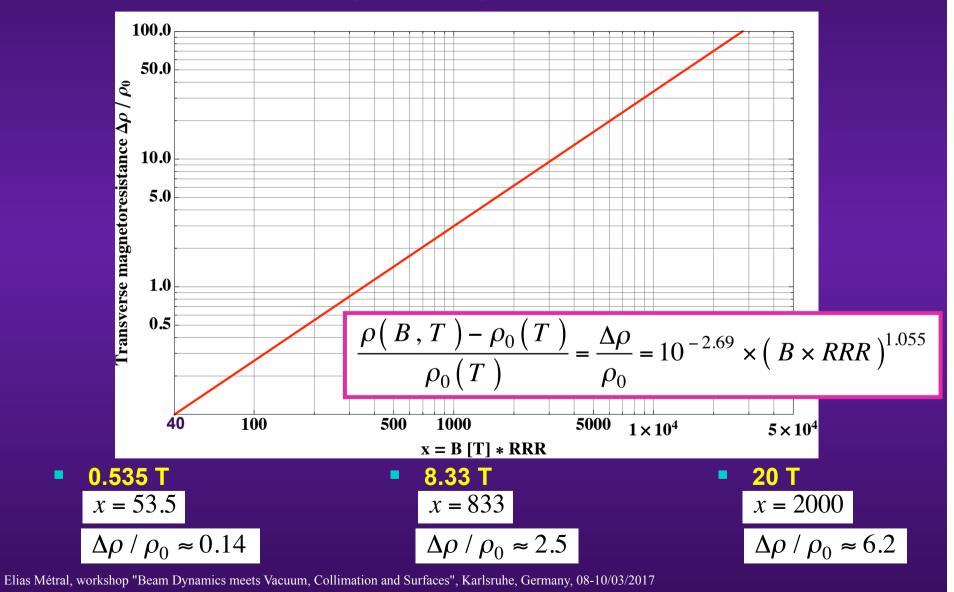
"Handbook of Accelerator Physics and Engineering", 2nd Printing, Edited by A.W. Chao and M. Tigner, p. 368

Elias Métral, workshop "Beam Dynamics meets Vacuum, Collimation and Surfaces", Karlsruhe, Germany, 08-10/03

Figure 2: Resistivity of several metals vs T.

APPENDIX C: MAGNETO-RESISTANCE

Increase of the resistivity with magnetic field => Kohler's rule



APPENDIX D: PUMPING HOLES

- The parameters for the current beam screen are
 - Length of the slots: L = 6,7,8,9 and 10 mm => Laverage = 8 mm
 - Width of the slots:
 - In the arcs: W = 1.5 mm
 - In the LSS: W = 1.0 mm
 - Beam screen thickness:
 - In the arcs: T = 1 mm SS + 0.075 mm Cu = 1.075 mm
 - In the LSS: T = 0.6 mm SS + 0.075 mm Cu = 0.675 mm